# **MBR4045WT**

## SWITCHMODE™ Power Rectifier

#### **Features and Benefits**

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 175°C Operating Junction Temperature
- 40 A Total (20 A Per Diode Leg)
- Pb–Free Package is Available\*

### Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

### **Mechanical Characteristics**

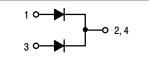
- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 4.3 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Rating: Human Body Model 3B Machine Model C

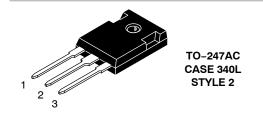


## **ON Semiconductor®**

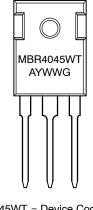
http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 40 AMPERES, 45 VOLTS





#### MARKING DIAGRAM



MBR4045WT = Device Code A = Assembly Loca

- = Year
- = Work Week

Y

G

WW

= Pb-Free Package

#### **ORDERING INFORMATION**

Device	Package	Shipping
MBR4045WT	TO-247	30 Units/Rail
MBR4045WTG	TO–247 (Pb–Free)	30 Units/Rail

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	45	V
Average Rectified Forward Current (Rated V <sub>R</sub> , T <sub>C</sub> = 125°C) Per Diode Per Device	I <sub>F(AV)</sub>	20 40	A
Peak Repetitive Forward Current, (Rated V <sub>R</sub> , Square Wave, 20 kHz, T <sub>C</sub> = 90°C) Per Diode	I <sub>FRM</sub>	40	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	400	A
Peak Repetitive Reverse Current (2.0 μs, 1.0 kHz)	I <sub>RRM</sub>	2.0	А
Storage Temperature Range	T <sub>stg</sub>	-65 to +175	°C
Operating Junction Temperature (Note 1)	TJ	-65 to +175	°C
Peak Surge Junction Temperature (Forward Current Applied)	T <sub>J(pk)</sub>	175	°C
Voltage Rate of Change	dv/dt	10,000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

#### THERMAL CHARACTERISTICS

Characteristic	Conditions	Symbol	Max	Unit
Maximum Thermal Resistance, Junction-to-Case	Min. Pad	$R_{\theta JC}$	1.4	°C/W
Maximum Thermal Resistance, Junction-to-Ambient	Min. Pad	$R_{\theta JA}$	50.1	°C/W

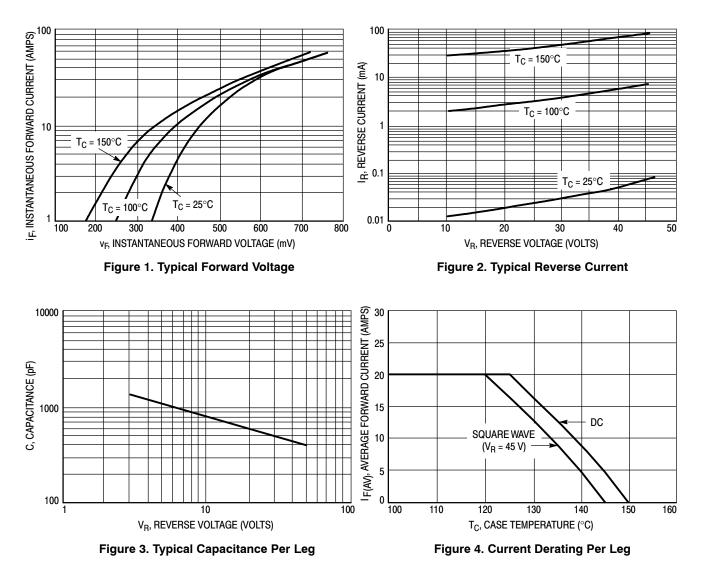
#### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Min	Typical	Max	Unit
Instantaneous Forward Voltage (Note 2) @ $I_F = 20$ Amps, $T_J = 25^{\circ}C$ @ $I_F = 20$ Amps, $T_J = 125^{\circ}C$ @ $I_F = 40$ Amps, $T_J = 25^{\circ}C$ @ $I_F = 40$ Amps, $T_J = 125^{\circ}C$	V <sub>F</sub>	- - -	0.52 0.47 0.65 0.63	0.70 0.60 0.80 0.75	V
Instantaneous Reverse Current (Note 2) @ Rated DC Voltage, T <sub>J</sub> = 25°C @ Rated DC Voltage, T <sub>J</sub> = 100°C	Ι <sub>R</sub>		0.09 7.5	1.0 50	mA

2. Pulse Test: Pulse Width = 300  $\mu s,$  Duty Cycle < 2.0%

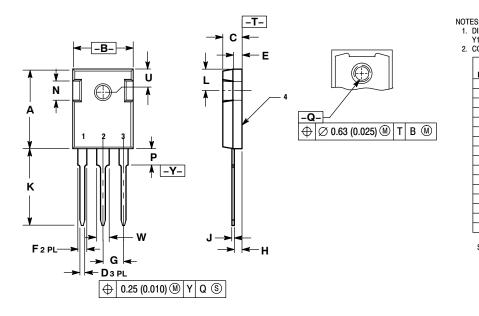
## **MBR4045WT**

### **TYPICAL ELECTRICAL CHARACTERISTICS**



#### PACKAGE DIMENSIONS

**TO-247** CASE 340L-02 ISSUE E



ISIONING	AND TOL	ERANCIN	IG PER AI	N;
A. 1982.				
	DIMENSI		METER	
MILLIN	IETERS	INCHES		
MIN	MAX	MIN	MAX	
20.32	21.08	0.800	8.30	
15.75	16.26	0.620	0.640	
4.70	5.30	0.185	0.209	
1.00	1.40	0.040	0.055	
1.90	2.60	0.075	0.102	
1.65	2.13	0.065	0.084	
5.45 BSC		0.215 BSC		
1.50	2.49	0.059	0.098	
0.40	0.80	0.016	0.031	
19.81	20.83	0.780	0.820	
5.40	6.20	0.212	0.244	
4.32	5.49	0.170	0.216	
	4.50		0.177	
3.55	3.65	0.140	0.144	
6.15 BSC		0.242 BSC		
2.87	3.12	0.113	0.123	
	A, 1982. ROLLING MILLIN 20.32 15.75 4.70 1.00 1.90 1.65 5.45 1.50 0.40 19.81 5.40 4.32  3.55 6.15	M. 1982.   ROLLING DIMENSI   MILLIMETERS   MIN MAX   20.32 21.08   15.75 16.26   4.70 5.30   1.00 1.40   1.90 2.60   1.65 2.13   5.45 BSC   1.50 2.49   0.40 0.80   19.81 20.83   5.40 6.20   4.32 5.49    4.50   3.55 3.65   6.15 BSC	In 1982.   A) 1982.   ACLLING DIMENSION: MILLI   MILLIMETERS INC   MIN MAX   MIN MAX   20.32 21.08 0.800   15.75 16.26 0.620   4.70 5.30 0.185   1.00 1.40 0.040   1.90 2.60 0.075   1.65 2.13 0.065   5.45 BSC 0.215 1.50   0.40 0.80 0.016   19.81 20.83 0.780   5.40 6.20 0.212   4.32 5.49 0.170    4.50    3.55 3.65 0.140	ACTION MILLIMETERS INCHES   MIN MAX MIN MAX   20.32 21.08 0.800 8.30   15.75 16.26 0.620 0.640   4.70 5.30 0.185 0.209   1.00 1.40 0.040 0.055   1.90 2.60 0.075 0.102   1.65 2.13 0.065 0.084   5.45 BSC 0.215 BSC   1.50 2.49 0.059 0.098   0.40 0.80 0.016 0.031   19.81 20.83 0.780 0.820   5.40 6.20 0.212 0.244   4.32 5.49 0.170 0.216    4.50  0.177   3.55 3.65 0.140 0.144   6.15 BSC 0.242 BSC

STYLE 2: PIN 1. ANODE 2. CATHODE (S) 3. ANODE 2

4. CATHODES (S)

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